LN175

GaAlAs Infrared Light Emitting Diode

For optical control systems

■ Features

- High-power output, high-efficiency: $P_O = 12 \text{ mW (typ.)}$
- Emitted light spectrum suited for silicon photodetectors: $\lambda_P = 900 \text{ nm}$ (typ.)
- Good radiant power output linearity with respect to input current
- Wide directivity: $\theta = 120^{\circ}$ (typ.)

■ Absolute Maximum Ratings $T_a = 25$ °C

Parameter	Symbol	Rating	Unit	
Power dissipation	P_{D}	170	mW	
Forward current	I_{F}	100	mA	
Pulse forward current *	I_{FP}	2	A	
Reverse voltage	V _R	3	V	
Operating ambient temperature	T _{opr}	-25 to +85	°C	
Storage temperature	T _{stg}	-40 to +100	°C	

Note) *: f = 100 Hz, Duty cycle = 0.1%

■ Electro-Optical Characteristics $T_a = 25^{\circ}C \pm 3^{\circ}C$

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Radiant power *	Po	$I_F = 100 \text{ mA}$	7.0	12.0	0/0.	mW
Reverse current	I_R	$V_R = 3 V$	6 19	0	10	μΑ
Forward voltage	V _F	$I_F = 100 \text{ mA}$	01/1	1.4	1.7	V
Terminal capacitance	Ct	$V_R = 0 \text{ V, } f = 1 \text{ MHz}$	100	50		pF
Peak emission wavelength	$\lambda_{ m P}$	$I_F = 100 \text{ mA}$	60,	900		nm
Spectral half band width	Δλ	$I_F = 100 \text{ mA}$		70		nm
Rise time	t _r	$I_{FP} = 100 \text{ mA}$		700		ns
Fall time	t_{f}	$I_{FP} = 100 \text{ mA}$		700		ns
Half-power angle	θ	The angle when the radiant power is halved.		120		0

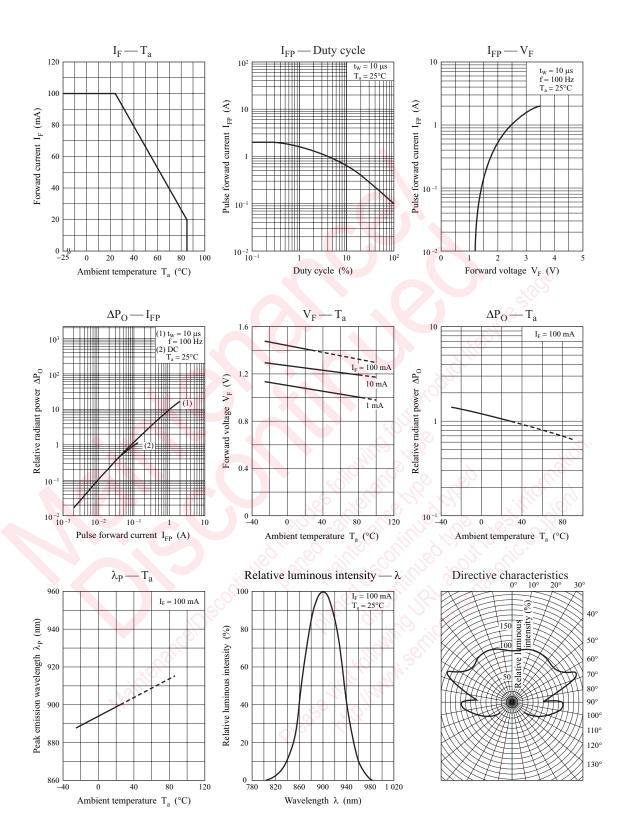
Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7031 measuring methods for diodes.

2. Cutoff frequency: 0.55 MHz

$$f_C: 10 \times log \frac{P_O \text{ at } f = f_C}{P_O \text{ at } f = 1 \text{ MHz}} = -3$$

3. *: A light detection element uses a silicon diode have proofread a load with a standard device.

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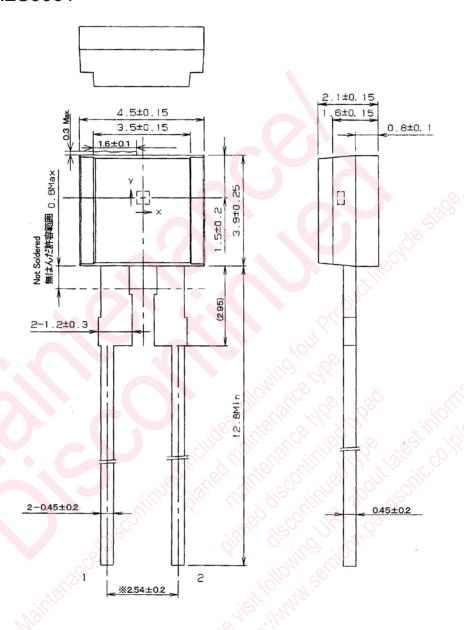


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■ Package (Unit: mm)

LETFSN2S0001



- Pin name
 - 1: Cathode
 - 2: Anode

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